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Correlation between microstructure and thermionic electron emission from Os-Ru thin films on dispenser cathodes

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Osmium-ruthenium (Os-Ru) alloy thin films are utilized on the dispenser cathode industry to enhance electron emission properties. It was discovered by Zalm et al. that coating Os on a standard dispenser cathode (B-type) would result in a cathode with a lower effective work function. Zalm et al. studied other coatings that also yielded cathodes with lower effective work functions, but Os has proved to give the greatest reduction in work function. The Os coating was eventually replaced by an Os-Ru alloy coating due to concerns about possible formation of highly toxic OsO₄. The Os-Ru alloy coating varies only negligibly from an Os coating in terms of effective work function reduction and its effect on cathode performance. Other refractory element coatings, such as osmium–iridium, have also been applied to dispenser cathodes in order to achieve properties similar to those of cathodes coated with Os-Ru. Dispenser cathodes with a top layer coating of a refractory metal are typically referred to as M-type dispenser cathodes.

Dispenser cathodes are essential components in devices that see service in space and military applications. As such, these devices require long lifetime and high reliability. There are two well accepted lifetime limiting factors for M-type dispenser cathodes: depletion of Ba from the impregnate and degradation of the coating. The impact of these factors is exacerbated at elevated temperature. The motivation behind the current study is to understand how the coating enhances electron emission and how it can be optimized to improve the lifetime of M-type dispenser cathodes.

The focus of many studies on M-type dispenser cathodes has been on chemical composition and barium adsorption/desorption. Additionally, the microstructure of the substrate material, W or a mixed-metal matrix, has been investigated. However, few studies have investigated the microstructure of the coating itself and how it relates to cathode performance. Liu et al. investigated a nanoparticle thin film coating of Ir and its effect on thermionic emission. It was found that the nanoparticle Ir thin film possessed similar emission capabilities to the traditional M-type cathode. However, no information on crystal structure or grain orientation was presented. Green et al. and Brion et al. studied Os-W coatings and the phases that developed in the coating during cathode operation. They found that the formation of a σ-phase alloy correlated with enhanced emission. Still, no crystallographic information was presented for the coatings that existed on the W substrates.

It is well known that the work function of a material varies for different crystallographic planes. In body-centered cubic W for example, the {100}, {110}, and {111} crystal faces have work functions of 4.63 eV, 5.22 eV, and 4.45 eV, respectively. When considering the work function of crystalline materials, crystallographic information should be discussed in order to achieve a more complete understanding. As first shown by Zalm et al., for M-type cathodes a higher work function base metal coating correlates with a low work function cathode. This counterintuitive trend was explained on the basis of a model with Ba on O metal, where Ba-O acts as a dipole that reduces the barrier to electron emission.
and where this effect is stronger for metals with higher work function. Additionally, Haas et al. and Cortenraad et al. pointed out that the crystallographic structure of the substrate surface should have a strong influence on the Ba-O dipole layer and therefore the overall work function of the cathode. Thus, while chemical composition, emission uniformity, and barium adsorption/desorption are important as aspects to consider in M-type dispenser cathodes, the microstructure of the coating should also be considered but is often not discussed.

Previous studies have shown that the microstructure of Os-Ru thin films can be controlled through the use of substrate biasing and that the microstructure has an influence on the emission properties of M-type dispenser cathodes. However, the exact nature of the influence is not well understood.

II. EXPERIMENT

A. Film preparation and characterization

Based on the work by Li et al., Os-Ru thin films with engineered microstructures were deposited simultaneously onto dispenser cathodes and W pellets. The dispenser cathodes and W pellets were manufactured by Semicon Associates in Lexington, KY. Both the cathodes and the W pellets had a diameter of 3.11 mm and were nominally 16% porous. The Os-Ru films were deposited at the University of Kentucky using DC magnetron sputtering (ATC Orion system, AJA International Inc.), and substrate bias was applied at predetermined levels to produce specific microstructures. The base pressure of the sputtering system was $6.67 \times 10^{-6}$ Pa ($5.0 \times 10^{-8}$ Torr) and the argon pressure during deposition was $0.33$ Pa ($2.5 \times 10^{-3}$ Torr). Table I summarizes the film deposition parameters and the corresponding microstructures.

![Table I. Deposition parameters and texture components of Os-Ru films.](image)

**FIG. 1.** SEM images showing grain growth of 10 W–150 nm [(a) and (b)] and Semicon [(c) and (d)] Os-Ru films after 1000 h in a CSD test. Images (a) and (c) show the films in their as-deposited states, while (b) and (d) show the films after 1000 h at elevated temperature. These images are representative of the grain growth seen in all samples after CSD testing.

B. Close-spaced diode testing

Dispenser cathodes with different Os-Ru film microstructures were sent to eBeam, Inc., for CSD testing. To provide a baseline for comparison, a commercially available, Os-Ru M-type dispenser cathode from Semicon Associates was also compared on the basis of knee temperature as determined from CSD testing.
included in the same test vehicle sent to eBeam, Inc. (Note that Semicon Associates uses RF diode sputtering to deposit their films, with no substrate biasing.) The cathodes were aged at 1100 °C (brightness temperature, which corresponds to a true temperature of 1171 °C) for 1000 h. Data were collected just after the initial activation (0 h), at 500 h, and at 1000 h. At each measurement interval and for each cathode, the change in anode current with cathode temperature was recorded for four different voltages applied to the cathode. For subsequent calculations, all brightness temperatures were converted to true temperatures.

III. RESULTS AND DISCUSSION

In the as-deposited state, all films exhibited small grains on the order of 10–20 nm as evidenced from the SEM and seen in Figs. 1(a) and 1(c). After 1000 h of CSD testing, grain size increased significantly to approximately 100–200 nm, as seen in Figs. 1(b) and 1(d). This growth highlighted the fact that significant atomic rearrangement occurred in the film. After characterizing the films with XRD it was found that some films had experienced a substantial change in film texture as well. Figure 2 compares the texture components in each film and demonstrates a clear difference in film texture. While the 5 W–550 nm film maintained its primarily basal texture, the multilayer, 10 W–150 nm, and standard Semicon film all transformed to either a {10-11} film texture or a mixed texture of {10-11} and {10-10}. Figure 3 shows an XRD scan of the multilayer coated cathode before and after CSD testing (with texture transformation induced by the CSD test). The Os-Ru peaks in the as-deposited state are present, albeit at low intensity. The peaks are more easily seen after CSD testing, and there is a clear preference for {10-11} orientation.

The CSD test data allowed determination of the knee temperature ($T_{knee}$) for cathodes at various stages of testing. Figure 4 shows the anode current versus temperature for each cathode over the course of the 1000 h test. Table II summarizes the cathode knee temperatures at three intervals during the 1000 h test. The knee temperature is often used as a means to compare cathode performance. The knee temperature is the point, on a plot of anode current versus cathode temperature, where electron emission changes from space charge limited to temperature limited. Dispenser cathodes are often operated just above $T_{knee}$. The temperature-limited regime of electron emission from a hot body is governed by the well-known Richardson equation

$$J = AT^2 \exp \left(-\frac{\phi}{kT}\right),$$

where $J$ is the anode current density, $A$ is theoretically 120 A cm$^{-2}$ K$^{-2}$, $T$ is temperature, $\phi$ is work function, and $k$ is the Boltzmann constant. Because temperature-limited emission rises exponentially with temperature, the high temperature portion of the curve can be taken as linear. Ideally,
the space charge limited region manifests itself as a plateau in current on a plot of anode current versus temperature. However, the transition from temperature limited to space charge limited is typically not sharp and occurs over a range of temperatures. This is typically attributed to a work function distribution on the surface of the cathode. Therefore, the space charge limited region on a plot of anode current versus temperature is typically represented as a line with a small positive slope. If lines are fitted to the space charge limited region and the linear portion of the temperature limited region, the intersection point can be taken as the knee temperature.

Table II indicates that for a given cathode, $T_{\text{knee}}$ either steadily improved over time or stayed relatively constant. The multilayer coated cathode displayed a significant improvement in $T_{\text{knee}}$ after 1000 h, while the 10 W–150 nm film and standard Semicon coated cathodes maintained fairly stable values of $T_{\text{knee}}$ from start to finish. The 5 W–550 nm coated cathode showed some improvement in $T_{\text{knee}}$ but not to the same extent as the multilayer coated cathode.

Along with the significant improvement in $T_{\text{knee}}$ for the multilayer coated cathode, film texture transformed from a mixture of \{0002\}, \{10-11\}, and \{10-10\} components, to a strong \{10-11\} texture. The transformation of the basal component into other components cannot be the sole source of the improvements, since the 10 W–150 nm film lost all of its basal component and yet retained a high $T_{\text{knee}}$. Therefore, it is proposed that the creation of the \{10-11\} texture component is responsible for the marked improvement in knee temperature. Other higher-index texture components were evaluated from XRD scans of all samples, and it is noted that the multilayer coated sample exhibited the lowest

### Table II. Cathode knee temperatures over 1000 h and associated texture components.

<table>
<thead>
<tr>
<th>Cathode coating</th>
<th>$T_{\text{knee}}$ (°C)</th>
<th>Major texture components at 1000 h</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>0 h</td>
<td>500 h</td>
</tr>
<tr>
<td>Multilayer</td>
<td>976</td>
<td>946</td>
</tr>
<tr>
<td>Semicon</td>
<td>940</td>
<td>930</td>
</tr>
<tr>
<td>5 W–550 nm</td>
<td>969</td>
<td>961</td>
</tr>
<tr>
<td>10 W–150 nm</td>
<td>975</td>
<td>969</td>
</tr>
</tbody>
</table>
number and proportion of higher-index grain orientations. The multilayer coated cathode had the highest proportion of {10-11} grains, suggesting that the strength of this texture (or lack of other texture components) contributed to the improvement in cathode performance.

To further evaluate cathode performance, the Richardson work function and the effective work function were extracted from CSD test data. The modified Richardson equation accounts for Schottky emission by replacing $\varphi$ with $(\varphi - \Delta \varphi)$, which reflects the change in work function due to applied electric field and is proportional to $V^{1/2}$. Therefore, a plot of $\log(J)$ versus $V^{1/2}$ at different temperatures for each cathode was constructed, from which the zero-field current density could be found through extrapolation. The zero-field current densities were then used to construct Richardson plots of $\log(J/T^2)$ versus $1/k T$ and the slope of the resultant line taken as the Richardson work function. The effective work function simply calculates the work function using Eq. (1) and data from temperature limited emission. Here, the knee temperature and the associated emission current were used to calculate an effective work function. Table III summarizes the calculated work functions of the cathodes coated with different Os-Ru microstructures and their associated knee temperatures. The multilayer cathode has a significantly lower Richardson work function (1.16 eV at 1000 h) than any of the other cathodes, while the 10 W–150 nm coated cathode has the highest at 1.72 eV. The effective work function and $T_{knee}$ correlate well, and therefore, the correlation of film texture with $T_{knee}$ also extends to work function. The correlation appears to be significantly non-linear for the lowest work function cathode. Richardson work function values are lower than expected. As seen in Table III, the effective work function values appear much more reasonable when compared to typical reported values for dispenser cathodes. The Semicon M-type Os-Ru coated cathodes have a reported work function of 1.8 eV. The Richardson work function calculated here is significantly lower than the reported value and could be due to errors inherent in the CSD test method, e.g., Ba resupply and geometric nonuniformities between the cathode and anode, which are exacerbated at high temperatures. The effective work function calculated using the knee temperature should represent some average of the work function distribution, since it uses a temperature and emission current from the transition region between temperature limited and space charge limited regimes. Therefore, if there were a strong bimodal work function distribution, the transition regions in CSD test curves and the effective work function calculated from these curves would better reflect this distribution. The fact that the effective work functions correspond more closely with typical values reported for M-type cathodes suggests that there are work function distributions present. Nonetheless, the correlation of work function with {10-11} remains.

The correlation of the development of {10-11} texture with decreasing $T_{knee}$ and work function could be related to the nature of the {10-11} plane in the HCP crystal structure. The difference in work function between crystal planes is usually attributed to planar density. Crystallographic orientations with low planar densities typically have low work functions. Orientations with higher planar densities will typically possess higher work functions. The work functions of crystal planes for HCP metals are not well characterized. However, available literature does show that the work functions of different HCP crystal planes do indeed differ. In rhenium, for example, the work function for the {0001}, {10-10}, and {10-11} planes are 5.59 eV, 5.37 eV, and 5.15 eV respectively.20 The {10-11} plane has a relatively low planar density (0.44 in Os-Ru), and therefore a comparatively low work function. The low work function of the {10-11} plane could correlate with the low effective work function of the multilayer coated cathode, since that coating has a strong {10-11} texture. Furthermore, it could also explain why some of the cathodes steadily decrease their $T_{knee}$ as microstructural changes are typically not instantaneous.

The Semicon film and the 5 W–550 nm film had similar thicknesses and resulted in fairly stable values of $T_{knee}$. Additionally, the 10 W–150 nm film had a similar thickness to the multilayer film yet showed little change in $T_{knee}$. This indicates that there may be some critical thickness or texture —or possibly a combination of both—that does not allow for marked emission improvement over time. Li et al. found that 5W biased films were quite stable, but the reason for this stability could be due to a combination of aspects such as texture and thickness, or film density.11

Much of the available literature on work function cites values that were obtained indirectly, using cathode emission test data. Directly measuring the work function of a dispenser cathode would provide valuable insight into the nature of the activated surface without the numerous sources of error associated with calculating the effective work function from CSD tests. True work function measurement coupled with CSD test data would allow for more complete evaluation of dispenser cathode performance.

### IV. SUMMARY AND CONCLUSIONS

One thousand hours of operation in a CSD test setup revealed that the microstructures of Os-Ru films undergo significant changes. There is a marked increase in grain size and a shift in texture that favors {10-10} and {10-11} texture components for films with low knee-temperatures. There appears to be a correlation between Os-Ru film texture and thermionic electron emission. It is proposed that formation of {10-11} texture results in improved cathode performance. Values for effective work function were calculated from the CSD data and were found to correlate with knee

### Table III. Comparison of knee temperature, calculated work function, and associated parameters for CSD test cathodes.

<table>
<thead>
<tr>
<th>Cathode coating</th>
<th>$T_{knee}$ ($C_R$)</th>
<th>Richardson work function (eV)</th>
<th>$A_R$ (A-cm⁻²-K⁻¹)</th>
<th>Effective work function (eV)</th>
</tr>
</thead>
<tbody>
<tr>
<td>Multilayer</td>
<td>934</td>
<td>1.16</td>
<td>0.054</td>
<td>1.90</td>
</tr>
<tr>
<td>Semicon</td>
<td>940</td>
<td>1.42</td>
<td>1.382</td>
<td>1.90</td>
</tr>
<tr>
<td>5 W–550 nm</td>
<td>952</td>
<td>1.61</td>
<td>5.321</td>
<td>1.93</td>
</tr>
<tr>
<td>10 W–150 nm</td>
<td>965</td>
<td>1.72</td>
<td>13.473</td>
<td>1.95</td>
</tr>
</tbody>
</table>
temperature. However, the magnitudes were lower than what would normally be expected, based on values for the reference cathode. Direct measurement of work function could provide a more complete measure of electron emission from dispenser cathodes.

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